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## Vishay General Semiconductor

# Dual TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.51 \text{ V}$  at  $I_F = 5 \text{ A}$ 

### eSMP® Series SMPD (TO-263AC)



#### **LINKS TO ADDITIONAL RESOURCES**



| PRIMARY CHARACTERISTICS                        |                 |  |  |  |
|--|-----------------|--|--|--|
| I <sub>F(AV)</sub>                             | 2 x 15 A        |  |  |  |
| V <sub>RRM</sub>                               | 120 V           |  |  |  |
| I <sub>FSM</sub>                               | 150 A           |  |  |  |
| $V_F$ at $I_F = 15$ A $(T_A = 125  ^{\circ}C)$ | 0.67 V          |  |  |  |
| T <sub>J</sub> max.                            | 175 °C          |  |  |  |
| Package  | SMPD (TO-263AC) |  |  |  |
| Circuit configuration                          | Common cathode  |  |  |  |

#### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

#### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)            |            |                                   |             |      |  |
|---|------------|-----------------------------------|-------------|------|--|
| PARAMETER   |            | SYMBOL                            | V30DM120C   | UNIT |  |
| Maximum repetitive peak reverse voltage   |            | V <sub>RRM</sub>                  | 120         | V    |  |
| Maximum average forward rectified current (fig. 1)                                | per device | ,                                 | 30          |      |  |
|   | per diode  | I <sub>F(AV)</sub>                | 15          | A    |  |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load |            | I <sub>FSM</sub>                  | 150         | А    |  |
| Voltage rate of change (rated V <sub>R</sub> )                                    |            | dV/dt                             | 10 000      | V/µs |  |
| Operating junction and storage temperature range                                  |            | T <sub>J</sub> , T <sub>STG</sub> | -40 to +175 | °C   |  |



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                        |                         |                               |      |      |      |  |  |
|---|------------------------|-------------------------|-------------------------------|------|------|------|--|--|
| PARAMETER   | TEST CONDITIONS        |                         | SYMBOL                        | TYP. | MAX. | UNIT |  |  |
| Instantaneous forward voltage per diode   | I <sub>F</sub> = 5 A   | T <sub>A</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup> | 0.59 | -    | V    |  |  |
|   | I <sub>F</sub> = 7.5 A |                         |                               | 0.66 | -    |      |  |  |
|   | I <sub>F</sub> = 15 A  |                         |                               | 0.88 | 0.97 |      |  |  |
|   | I <sub>F</sub> = 5 A   | T <sub>A</sub> = 125 °C |                               | 0.51 | -    |      |  |  |
|   | I <sub>F</sub> = 7.5 A |                         |                               | 0.56 | -    |      |  |  |
|   | I <sub>F</sub> = 15 A  |                         |                               | 0.67 | 0.76 |      |  |  |
| Reverse current per diode   | V <sub>R</sub> = 90 V  | T <sub>A</sub> = 25 °C  | I <sub>R</sub> (2)            | 5    | -    | μΑ   |  |  |
|   |                        | T <sub>A</sub> = 125 °C |                               | 3.1  | -    | mA   |  |  |
|   | V <sub>R</sub> = 120 V | T <sub>A</sub> = 25 °C  |                               | -    | 800  | μA   |  |  |
|   |                        | T <sub>A</sub> = 125 °C |                               | 6    | 27   | mA   |  |  |

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |            |                          |           |      |  |
|---|------------|--------------------------|-----------|------|--|
| PARAMETER   |            | SYMBOL                   | V30DM120C | UNIT |  |
|   | per diode  | - R <sub>θJC</sub>       | 2.2       | °C/W |  |
| Typical thermal resistance  | per device |                          | 1.2       |      |  |
|   | per device | R <sub>0</sub> JA (1)(2) | 48        | 1    |  |

#### **Notes**

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

(2) Free air, without heatsink

| ORDERING INFORMATION (Example) |                    |                 |              |               |                                    |
|--------------------------------|--------------------|-----------------|--------------|---------------|------------------------------------|
| PACKAGE                        | PREFERRED P/N      | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |
| SMPD (TO-263AC)                | V30DM120C-M3/I     | 0.55            | I            | 2000/reel     | 13" diameter plastic tape and reel |
| SMPD (TO-263AC)                | V30DM120CHM3/I (1) | 0.55            | I            | 2000/reel     | 13" diameter plastic tape and reel |

#### Note

(1) AEC-Q101 qualified

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

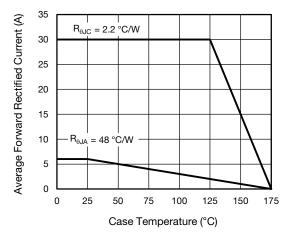


Fig. 1 - Forward Current Derating Curve

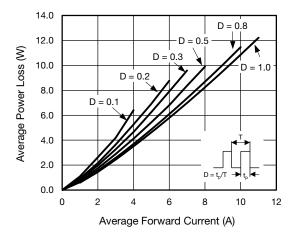


Fig. 2 - Forward Power Loss Characteristics Per Diode



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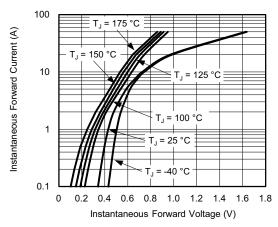


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

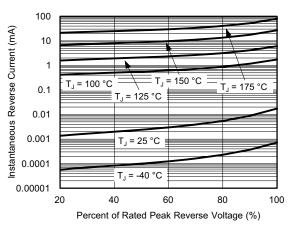


Fig. 4 - Typical Reverse Characteristics Per Diode

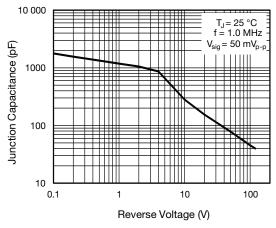


Fig. 5 - Typical Junction Capacitance Per Diode

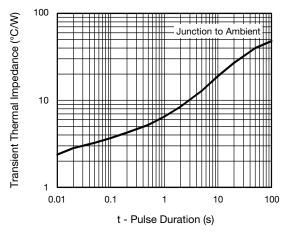


Fig. 6 - Typical Transient Thermal Impedance Per Device

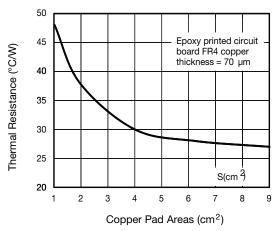
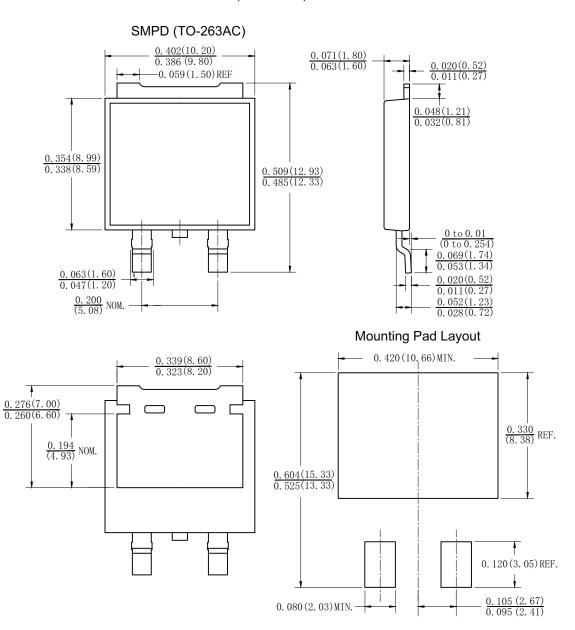


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas



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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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